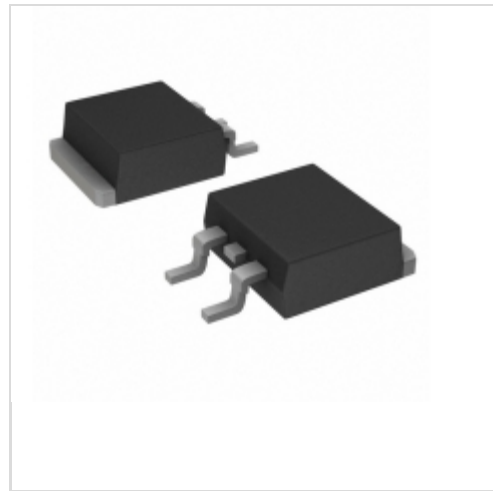


**UGB8DTHE3/45**

**Vishay / Semiconductor - Diodes Division**

DIODE GEN PURP 200V 8A TO263AB

Lead free / RoHS Compliant

Discrete Semiconductor Products

[UGB8DTHE3/45.pdf](#)

We can supply Vishay / Semiconductor - Diodes Division UGB8DTHE3/45, use the request quote form to request UGB8DTHE3/45 price, Vishay / Semiconductor - Diodes Division Datasheet PDF and lead time. Zeano.com is a professional electronic components distributor. With 3+ Million line items of available electronic components can ship in short lead-time, over 250 thousand part numbers of electronic components in stock for immediately delivery, which may include part number UGB8DTHE3/45. The price and lead time for UGB8DTHE3/45 depending on the quantity required, availability and warehouse location.

**Out Stock**
**0 pcs**

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

## Shopping Process

**1**
**Confirm the product**
**2**
**submit the order**
**3**
**payment**
**4**
**wait for delivery**
**5**
**receive the goods**

## Specifications

<b>Voltage - Forward (Vf) (Max) @ If:</b>	1V @ 8A
<b>Voltage - DC Reverse (Vr) (Max):</b>	200V
<b>Supplier Device Package:</b>	TO-263AB
<b>Speed:</b>	Fast Recovery = 200mA (Io)
<b>Series:</b>	-
<b>Reverse Recovery Time (trr):</b>	30ns
<b>Packaging:</b>	Tube
<b>Package / Case:</b>	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
<b>Operating Temperature - Junction:</b>	-55°C ~ 150°C
<b>Mounting Type:</b>	Surface Mount
<b>Diode Type:</b>	Standard
<b>Current - Reverse Leakage @ Vr:</b>	10µA @ 200V
<b>Current - Average Rectified (Io):</b>	8A
<b>Capacitance @ Vr, F:</b>	-

## Related products


**UGB8FT-E3/81**

DIODE GEN PURP 300V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


**UGB8DTHE3/81**

DIODE GEN PURP 200V 8A TO263AB

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RFQ


**UGB8FTHE3/81**

DIODE GEN PURP 300V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


**UGB8CTHE3/81**

DIODE GEN PURP 150V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


**UGB8DT-E3/45**

DIODE GEN PURP 200V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


**UGB8DT-E3/81**

DIODE GEN PURP 200V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


**UGB8CTHE3/45**

DIODE GEN PURP 150V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


**UGB8GT**

N/A

RFQ


**UGB8CT-E3/81**

DIODE GEN PURP 150V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ


**UGB8FTHE3/45**

DIODE GEN PURP 300V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ

## Guess You May Looking For


**SIT1602BC-33-25N-77.760000T**

-20 TO 70C, 5032, 50PPM, 2.5V, 7

[SITIME](#)

RFQ


**SIT1602BC-83-XXE-30.000000Y**

-20 TO 70C, 7050, 50PPM, 2.25V-3

[SITIME](#)

RFQ


**SIT1602BC-21-18S-4.096000D**

-20 TO 70C, 3225, 20PPM, 1.8V, 4

[SITIME](#)

RFQ


**SIT1602BC-22-33N-40.500000D**

-20 TO 70C, 3225, 25PPM, 3.3V, 4

[SITIME](#)

RFQ


**SIT8008BIF13-XXS-6.780000E**

OSC MEMS 6.7800MHZ LVCMOS SMD

[SITIME](#)

RFQ


**SIT1602BC-21-30N-31.250000E**

-20 TO 70C, 3225, 20PPM, 3.0V, 3

[SITIME](#)

RFQ


**SIT1602BI-81-33S-33.000000T**

-40 TO 85C, 7050, 20PPM, 3.3V, 3

[SITIME](#)

RFQ


**SIT1602BI-31-28N-28.636300Y**

-40 TO 85C, 5032, 20PPM, 2.8V, 2

[SITIME](#)

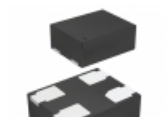
RFQ


**SIT1602BI-32-25N-35.840000Y**

-40 TO 85C, 5032, 25PPM, 2.5V, 3

[SITIME](#)

RFQ


**SIT1602BC-72-XXE-38.400000G**

-20 TO 70C, 2016, 25PPM, 2.25V-3

[SITIME](#)

RFQ